

Sem.	Subject code	Course title	No. of hours	Credits	Paper type
V	17U5PMC5	Analog electronics	5	5	Major Core

Objectives:

(i) To introduce the students to basics of circuit theory (ii) To impregnate knowledge of active devices and their applications to the students.

Learning outcome:

(i) The student will be able to solve problems involving circuits and (ii) Design circuits for various physical applications.

Unit I: Network Theorem and Semiconductor diodes

Maximum power transfer theorem-Thevenin's theorem-Norton's theorem-Solving problems– Intrinsic Semiconductor–Extrinsic Semiconductor–N type and P type Semiconductor– Semiconductor diode–Crystal diode as a rectifier–Important terms-Half wave rectifier-Efficiency– Full wave bridge rectifier-Efficiency-Ripple factor-Comparison of rectifier-Filter circuits-Voltage stabilization-Zener diode -Zener as voltage stabilizer.

Unit II: Transistors

Transistor–Naming the transistor terminals-Action-Symbols-Transistor as an amplifier-Transistor connections(CB,CE,CC)-Characteristics (CE only)-DC load line analysis-Operating points- Methods of transistor biasing–Voltage divider bias.

Unit III: Hybrid Parameter and Transistor amplifiers

Hybrid parameter-Determination of h-parameter-Equivalent circuit-Performance of linear circuit in h parameter–The h-parameters of a transistor–Nomenclature for transistor h-parameters– Transistor circuit performance in h-parameters – Single stage transistor amplifier – Transistor amplification and its graphical demonstration-Practical circuits of transistor amplifier–RC coupled amplifier-Performance of power amplifier-Classification of power amplifier.

Unit IV: Oscillators and Multi-vibrators

Feedback–Principle of negative feedback amplifier-Advantages of negative feedback-Feedback circuit–Oscillators-Types of sinusoidal oscillations-Oscillatory circuits-Undamped oscillation from tank circuit-Explanation of Barkhausen criterion-Hartley oscillator–Multivibrators-Astable multivibrator.

Unit V: Field Effect Transistors

Introduction–Types of FETs–JFET–Working principle of JFET–Difference between JFET and Bipolar transistors–JFET as an amplifier–Output characteristics of JFET–Important terms– Expression for drain current–Advantages of JFET–Parameters of JFET–Relation among JFET parameter.

Text Book(s)

1. Principles of electronics, V.K.Mehta & Rohit Mehta, XIth Edn., S. Chand and Co. Ltd (2013)

Unit I: Sections 1.12-1.16,5.1,5.14-5.16,6.1-6.2,6.8-6.11,6.13-6.15,6.18,6.20,6.21,6.24,6.25,6.27

Unit II: Sections 8.1-8.8,8.10,8.12,8.13,8.17,8.18,9.6,9.7,9.12,24.1-24.7

Unit III: Sections 10.1 – 10.4, 11.1, 11.2,11.5, 12.5,12.6,13.1-13.5

Unit IV: Sections 14.1-14.4,14.7,14.1,18.10-18.12

Unit V: Sections 19.1-19.8,19.10-19.14

Books for Reference:

1. Basic Electronics:Solid State, B.L.Theraja, S.Chand & Co., New Delhi, (2006).
 2. A Text Book of applied electronics, R.S. Sheda, S.Chand & Co., New Delhi, (2003).
 3. Electronic principles by Albert Malvino & David Bates, 7th Edn., Mc Graw Hill Education Pvt. Ltd., 21st Reprint, (2017)
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Websites:

1. <https://ocw.mit.edu/courses/electrical-engineering-and-computer-science/6-101-introductory-analog-electronics-laboratory-spring-2007/>
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